

PROCEEDINGS OF SPIE

Semiconductor Lasers and Laser Dynamics III

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Editors

7–9 April 2008

Strasbourg, France

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Published by
SPIE

Volume 6997

Proceedings of SPIE, 0277-786X, v. 6997

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

The papers included in this volume were part of the technical conference cited on the cover and title page. Papers were selected and subject to review by the editors and conference program committee. Some conference presentations may not be available for publication. The papers published in these proceedings reflect the work and thoughts of the authors and are published herein as submitted. The publisher is not responsible for the validity of the information or for any outcomes resulting from reliance thereon.

Please use the following format to cite material from this book:

Author(s), "Title of Paper," in *Semiconductor Lasers and Laser Dynamics III*, edited by Krassimir P. Panajotov, Marc Sciamanna, Angel A. Valle, Rainer Michalzik, Proceedings of SPIE Vol. 6997 (SPIE, Bellingham, WA, 2008) Article CID Number.

ISSN 0277-786X
ISBN 9780819471956

Published by
SPIE
P.O. Box 10, Bellingham, Washington 98227-0010 USA
Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445
SPIE.org

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Printed in the United States of America.

Publication of record for individual papers is online in the SPIE Digital Library.



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